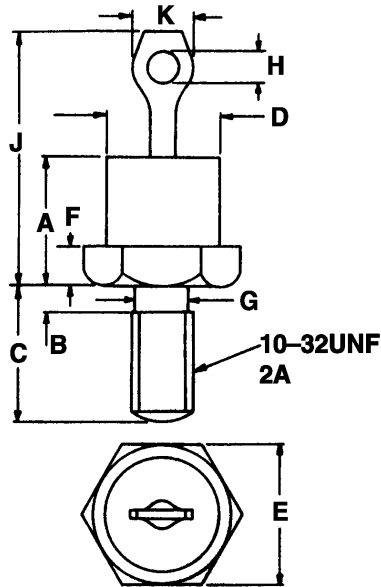


MECHANICAL DATA

Dimensions in mm(inches)



VOLTAGE REGULATOR DIODES

FEATURES

The BZY93 series is a range of medium power silicon voltage regulator diodes for general purpose use in a DO-4 outline metal case encapsulation for stud mounting.

Both polarity types are available, BZY93C having stud cathode and BZY93C-R having stud anode.

Dim.	Min.	Nom.	Max.
A	–	–	10.28
B	–	–	1.80
C	10.72	–	11.50
D	–	–	10.77Ø
E	10.80Ø	–	11.10Ø
F	–	–	4.40
G	4.20Ø	–	4.80Ø
H	1.60Ø	–	1.80Ø
J	–	–	20.32
K	–	–	6.35

ABSOLUTE MAXIMUM RATINGS

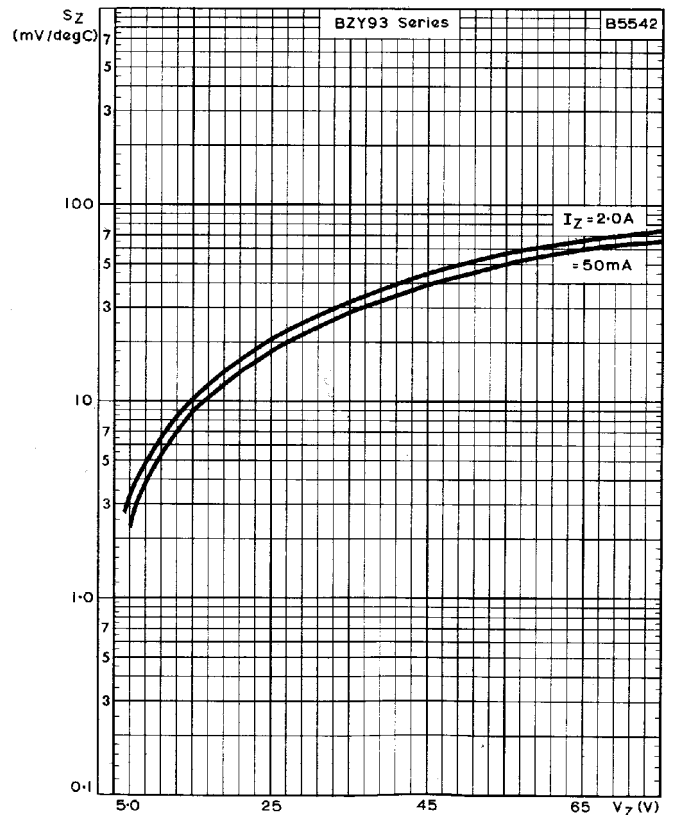
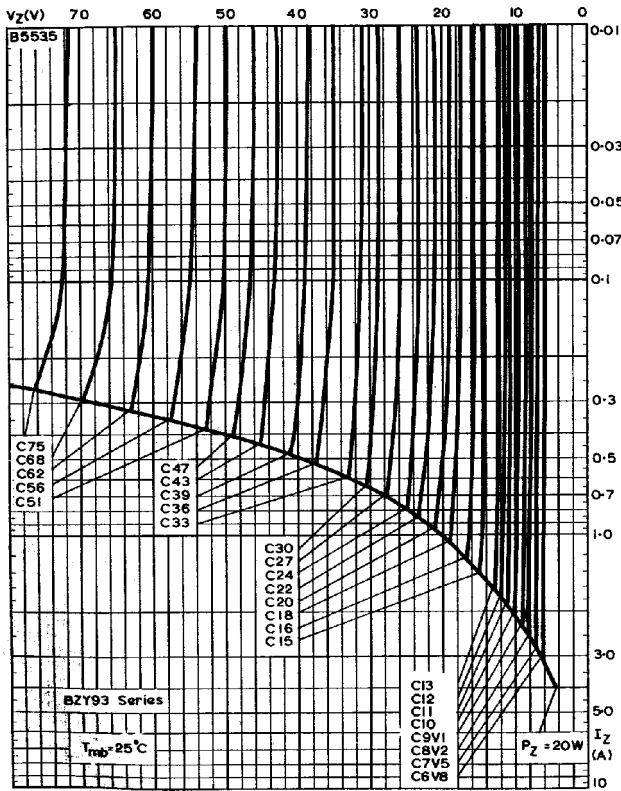
$I_{ZM}^{max.}$		20A
$I_{FRM}^{max.}$		15A
$I_{F(AV)}^{max.}$	Averaged over any 20ms period	5A
$P_{TOT}^{max.}$	$T_{MB} = 75^{\circ}C$	20W
	$T_{MB} = 100^{\circ}C$	15W
$P_{Z(sur)}^{max.}$	$T_{MB} = 75^{\circ}C$	500W
T_{STG}	Storage Temperature Range	-55 to +175°C
$T_{Jmax.}$	Maximum Junction Temperature	175°C
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	5°C/W
$R_{\theta J-MB}$	Thermal Resistance Junction to Mounting Base	50°C/W
$R_{\theta MB-H}$	Thermal Resistance Mounting Base to Heatsink	0.6°C/W
	Derating factor $T_{MB} > 75^{\circ}C$	0.2W/°C

ELECTRICAL CHARACTERISTICS ($T_{mb} = 25^{\circ}\text{C}$) UNLESS OTHERWISE STATED

Product	Test I_Z (A)	V_Z^1 @ Test I_Z (V)		R_Z^1 @ Test I_Z (Ω)		S_Z^1 (mV/ $^{\circ}\text{C}$)	I_R (μA)	At	V_R (V)
		Min.	Max.	Typ.	Max.	Typ.	Max.		
C6V8	2.0	6.4	7.2	0.04	0.2	2.5	100		2.0
C7V5	2.0	7.0	7.9	0.04	0.3	3.0	100		2.0
C8V2	2.0	7.7	8.7	0.05	0.3	4.0	100		5.6
C9V1	1.0	8.5	9.6	0.07	0.5	5.0	50		6.2
C10	1.0	9.4	10.6	0.07	0.5	7.0	50		6.8
C11	1.0	10.4	11.6	0.08	1.0	7.5	50		7.5
C12	1.0	11.4	12.7	0.08	1.0	8.0	50		8.2
C13	1.0	12.4	14.1	0.08	1.0	8.5	50		9.1
C15	1.0	13.8	15.6	0.10	1.2	10.0	50		10.0
C16	0.5	15.3	17.1	0.18	1.2	11.0	50		11.0
C18	0.5	16.8	19.1	0.20	1.5	12.0	50		12.0
C20	0.5	18.8	21.2	0.20	1.5	14.0	50		13.0
C22	0.5	20.8	23.3	0.21	1.8	16.0	50		15.0
C24	0.5	22.7	25.9	0.22	2.0	18.0	50		16.0
C27	0.5	25.1	28.9	0.25	2.0	21.0	50		18.0
C30	0.5	28.0	32.0	0.30	2.5	25.0	50		20.0
C33	0.5	31.0	35.0	0.32	3.0	30.0	50		22.0
C36	0.2	34.0	38.0	0.75	4.0	32.0	50		24.0
C39	0.2	37.0	41.0	0.85	5.0	35.0	50		27.0
C43	0.2	40.0	46.0	0.9	6.5	40.0	50		30.0
C47	0.2	44.0	50.0	1.0	7.0	45.0	50		33.0
C51	0.2	48.0	54.0	1.2	7.5	50.0	50		36.0
C56	0.2	52.0	60.0	1.3	8.0	55.0	50		39.0
C62	0.2	58.0	66.0	1.5	9.0	60.0	50		43.0
C68	0.2	64.0	72.0	1.8	10.0	65.0	50		47.0
C75	0.2	70.0	79.0	2.0	10.5	70.0	50		51.0

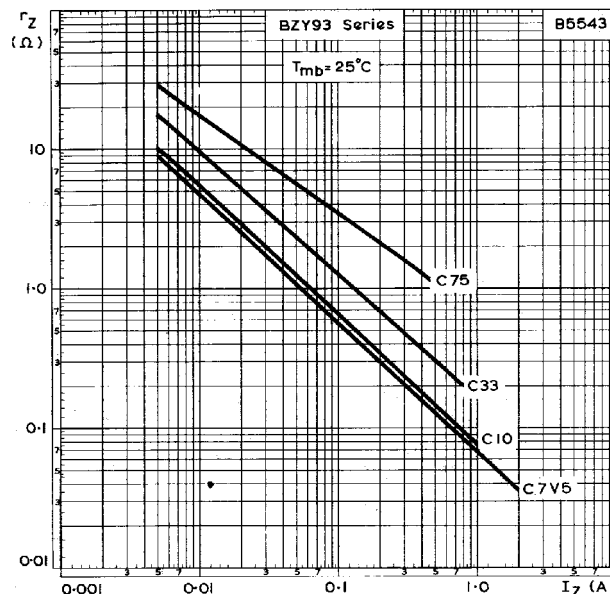
Notes

1. Pulse Test: $t_p \leq 100\mu\text{s}$, $\delta \leq 0.1\%$.

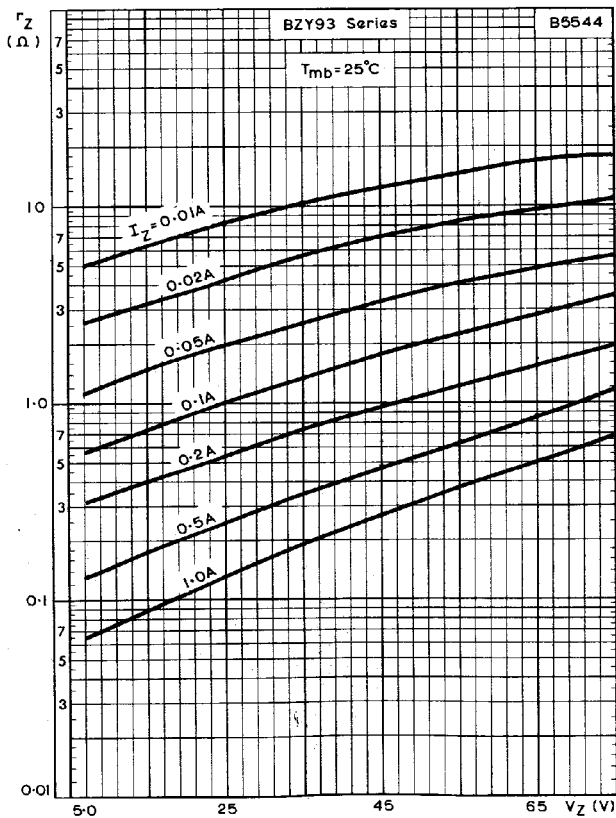


TYPICAL STATIC ZENER CHARACTERISTICS

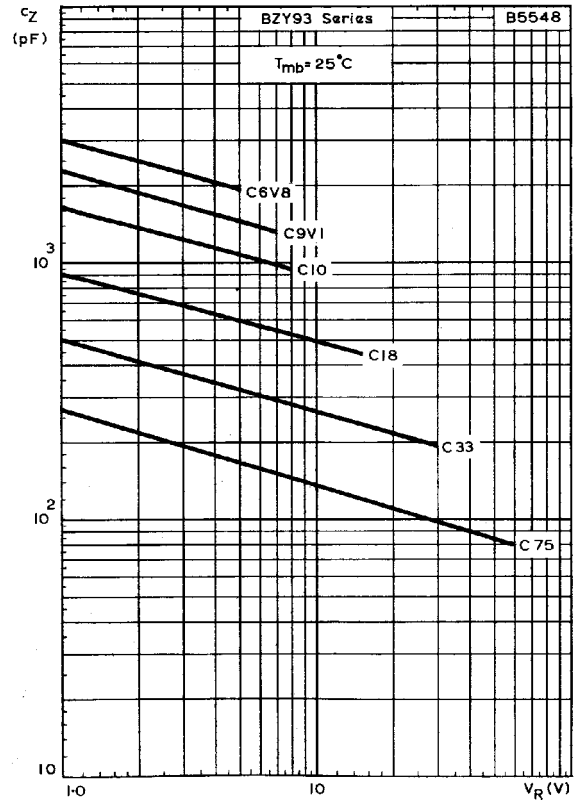
TYPICAL TEMPERATURE COEFFICIENT vs ZENER VOLTAGE



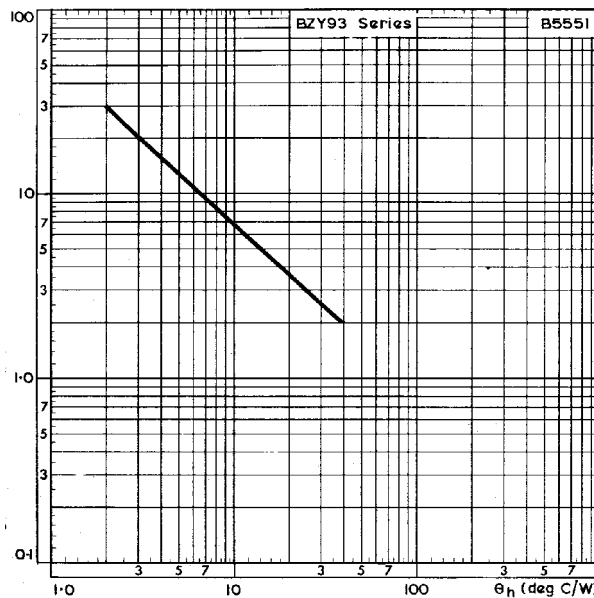
TYPICAL DYNAMIC IMPEDANCE vs ZENER CURRENT



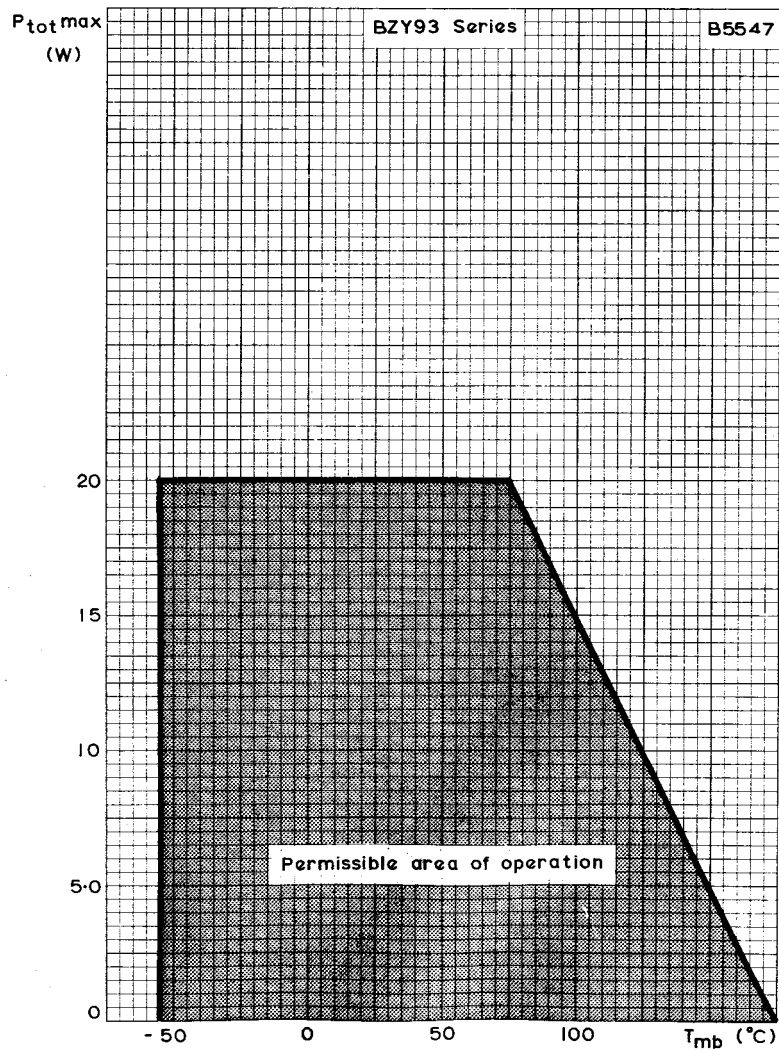
TYPICAL DYNAMIC IMPEDANCE vs ZENER VOLTAGE



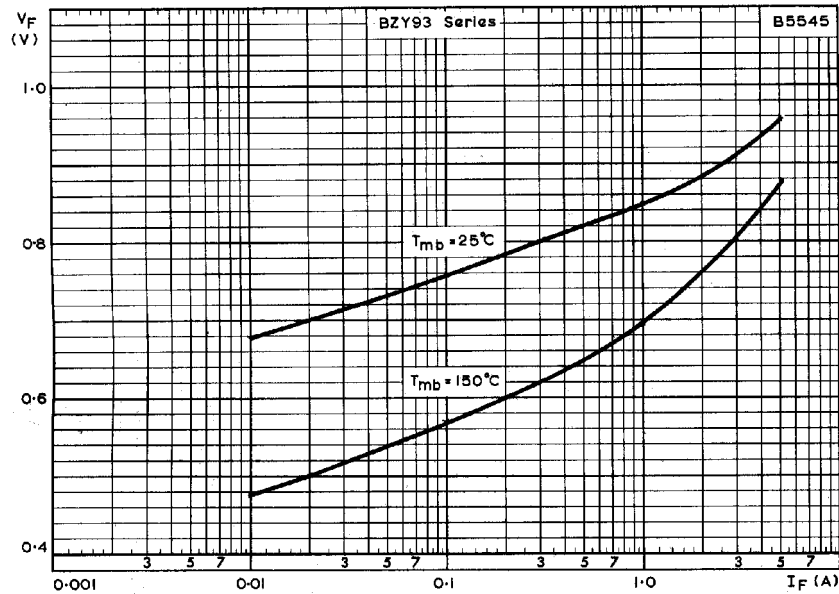
TYPICAL ZENER CAPACITANCE vs REVERSE VOLTAGE



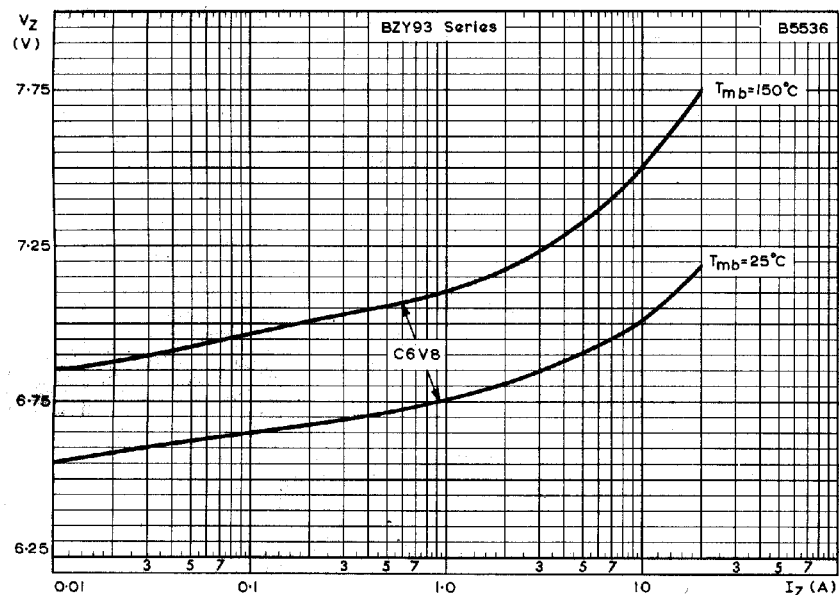
THERMAL RESISTANCE vs SQUARE SIDE VERTICALLY MOUNTED HEATSINK OF 16 s.w.g. (1.625mm) NORMAL BRIGHT FINISH.



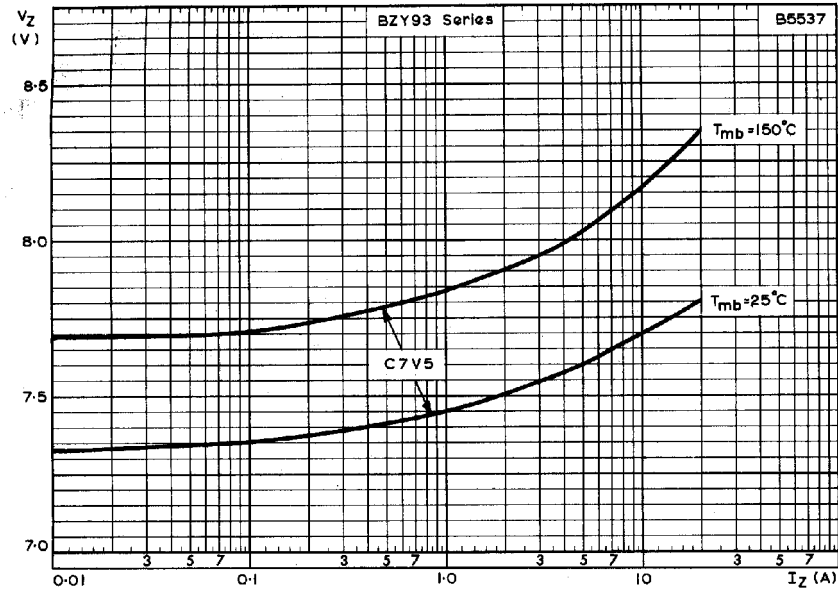
MAXIMUM TOTAL DISSIPATION vs MOUNTING BASE TEMPERATURE



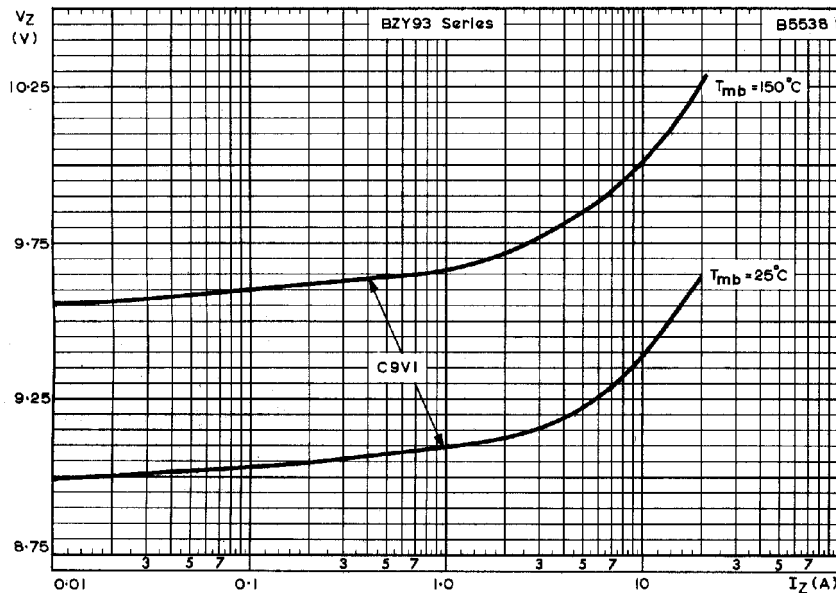
TYPICAL DYNAMIC FORWARD CHARACTERISTICS



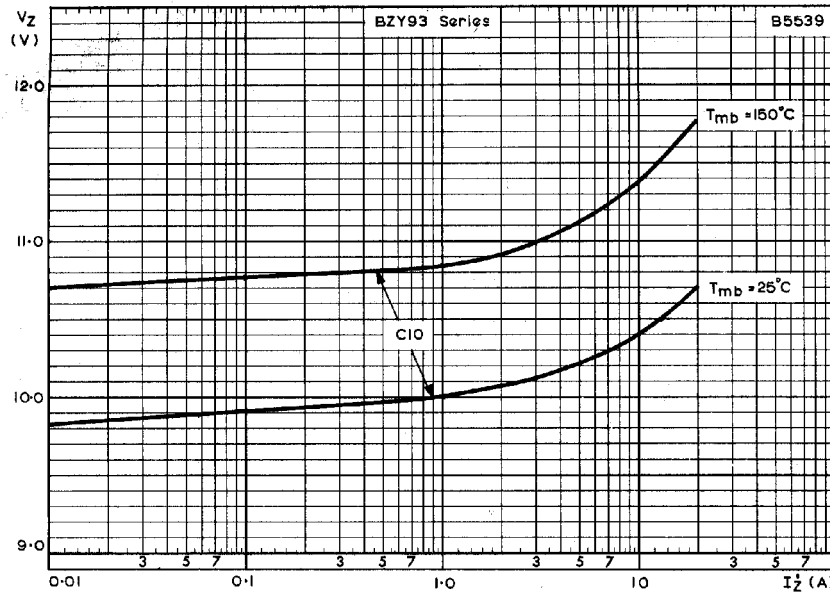
TYPICAL DYNAMIC ZENER CHARACTERISTICS FOR 6.8V DEVICE



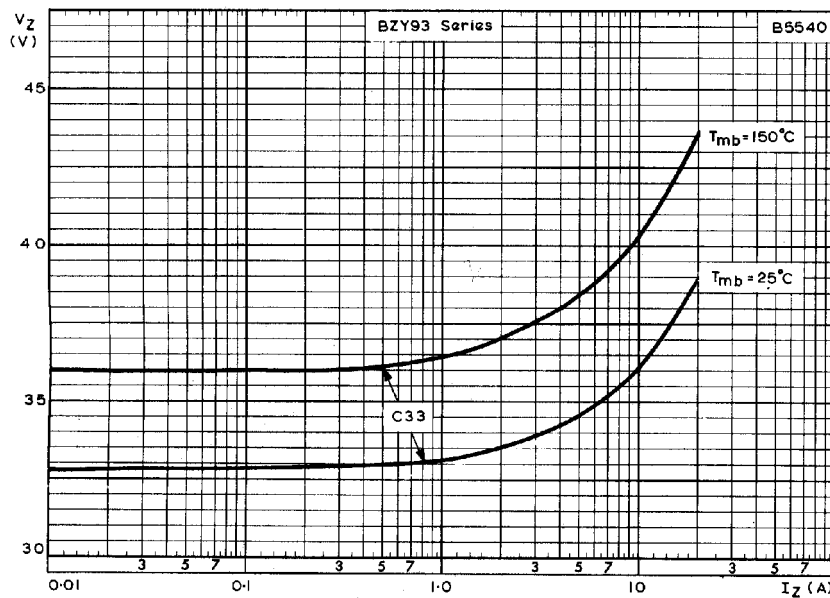
TYPICAL DYNAMIC ZENER CHARACTERISTICS FOR 7.5V DEVICE



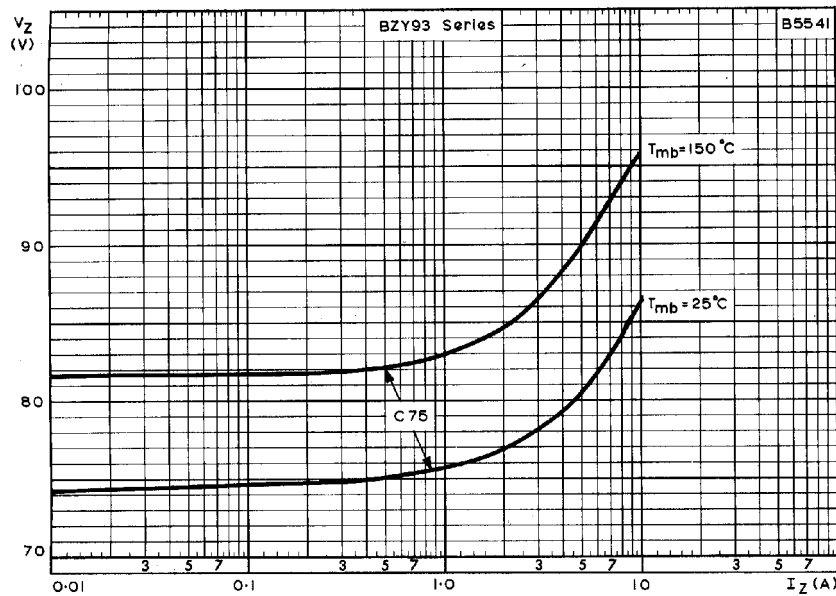
TYPICAL DYNAMIC ZENER CHARACTERISTICS FOR 9.1V DEVICE



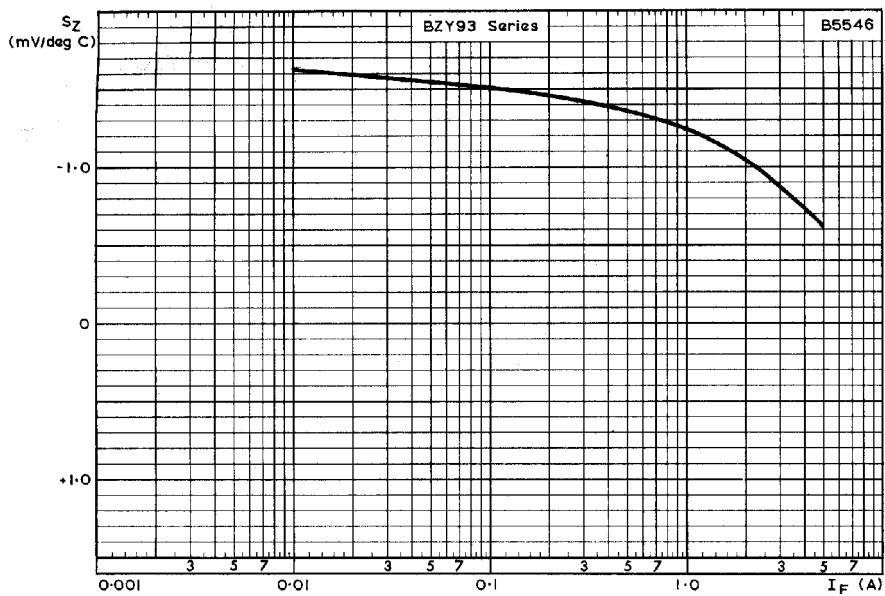
TYPICAL DYNAMIC ZENER CHARACTERISTICS FOR 10V DEVICE



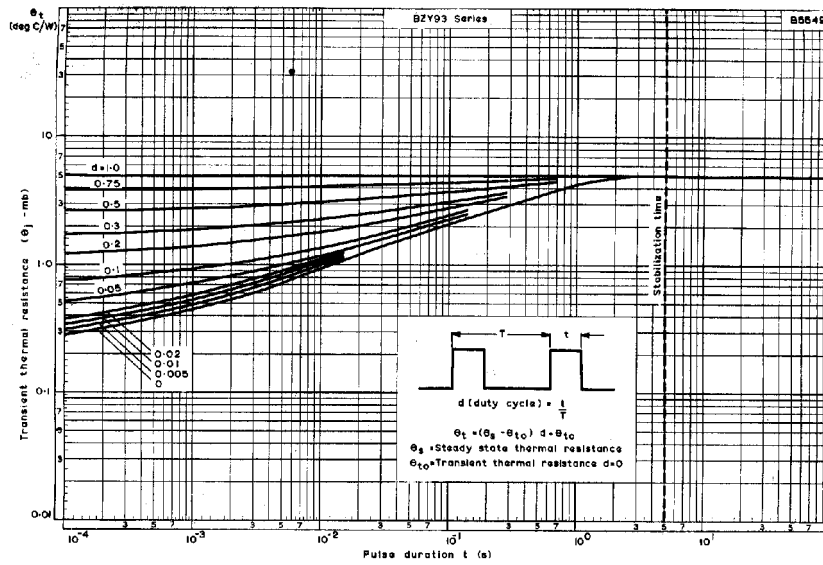
TYPICAL DYNAMIC ZENER CHARACTERISTICS FOR 33V DEVICE



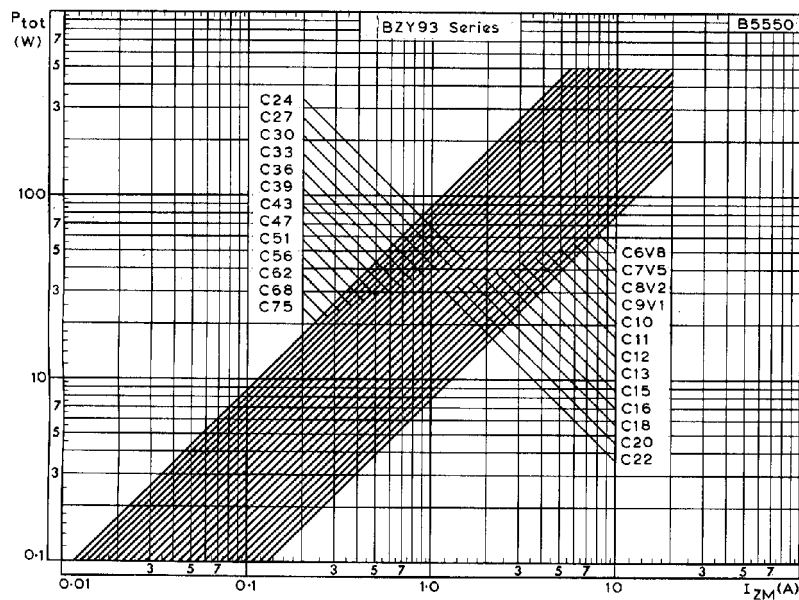
TYPICAL DYNAMIC ZENER CHARACTERISTICS FOR 75V DEVICE



TYPICAL FORWARD VOLTAGE TEMPERATURE COEFFICIENT vs FORWARD CURRENT



TRANSIENT THERMAL RESISTANCE FOR VARIOUS DUTY FACTORS vs PULSE DURATION



MAXIMUM ZENER DISSIPATION vs ZENER CURRENT